Seat No.:	Enrolment No.
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## **GUJARAT TECHNOLOGICAL UNIVERSITY**

BE - SEMESTER-III • EXAMINATION - WINTER • 2014

	•	Code: 2133901 Date: 30-12-2014 Name: Fundamentals of Solid State Technology	
Time: 02.30 pm - 05.00 pm Instructions:  Total Marks: 70			
	1. 2. 3.	Attempt all questions.  Make suitable assumptions wherever necessary.  Figures to the right indicate full marks.	
Q.1	(a) (b)	Define Unit cell. Explain Seven Crystal System. Explain Features of miller indices. Draw (100) Plain.	07 07
Q.2	(a) (b)	Explain defects in solid materials.  Explain X-ray diffraction Technique for identify crystal structure.  OR	07 07
	<b>(b)</b>	Write Applications of X-Ray diffraction techniques	07
Q.3	(a) (b)	Explain Lattice vibration in Solids Write notes on thermal heat capacity in solids OR	07 07
Q.3	(a) (b)	Explain Einstein theory for molar heat capacity.  Describe limitation of Einstein theory	07 07
Q.4	(a) (b)	Define extrinsic semiconductor. Describe acceptor and donor level in extrinsic semiconductor.  Explain band diagram of p-n junction diode.  OR	07
Q.4	(a) (b)	Explain Hall effect with neat diagram. Explain Rectification by p-n Junction diode	07 07
Q.5	(a) (b)	Write Applications of Dielectric Materials.  Define polarization. Explain different types of polarization in dielectric materials  OR	07 07
Q.5	(a) (b)	Write short note on magnetic materials.  Describe optical and thermal properties of semiconductor	07 07

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